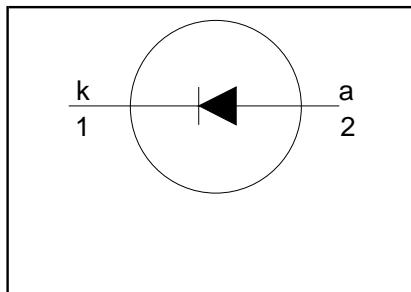


Rectifier diode fast, high-voltage

BY559-1500

FEATURES

- Low forward volt drop
- Low forward recovery voltage
- Fast switching
- Soft recovery characteristic
- High thermal cycling performance
- Low thermal resistance

SYMBOL**QUICK REFERENCE DATA**

$V_R = 1500 \text{ V}$
$V_F \leq 1.2 \text{ V}$
$V_{fr} \leq 14 \text{ V}$
$t_{fr} \leq 250 \text{ ns}$
$I_{F(AV)} = 10 \text{ A}$
$I_{FSM} \leq 100 \text{ A}$

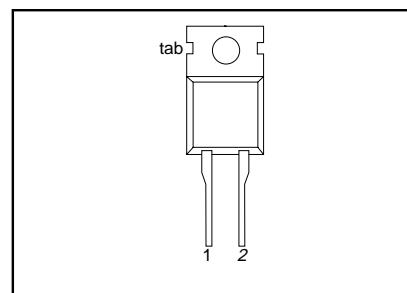
GENERAL DESCRIPTION

Glass-passivated double diffused rectifier diode featuring fast forward recovery and low forward recovery voltage. The device is intended for use in multi-sync monitor horizontal deflection circuits with maximum scan rates from 82 kHz to 120 kHz.

The BY559 series is supplied in the conventional leaded SOD59 (TO220AC) package.

PINNING

PIN	DESCRIPTION
1	cathode
2	anode
tab	cathode

SOD59 (TO220AC)**LIMITING VALUES**

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{RRM}	Peak repetitive reverse voltage		-	1500	V
V_{RWM}	Crest working reverse voltage		-	1300	V
I_{FWM}	Peak working forward current		-	10	A
I_{FRM}	Peak repetitive forward current		-	150	A
I_{FSM}	Peak non-repetitive forward current		-	180	A
		$f = 120 \text{ kHz}; t = 100 \mu\text{s}$	-	200	A
		$t = 10 \text{ ms}$	-		
		$t = 8.3 \text{ ms}$	-		
		sinusoidal; $T_j = 150^\circ\text{C}$ prior to surge; with reapplied $V_{RWM(max)}$	-40	150	°C
T_{stg}	Storage temperature		-	150	°C
T_j	Operating junction temperature		-	150	°C

 THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th j-mb}$	Thermal resistance junction to mounting base		-	-	1.0	K/W
$R_{th j-a}$	Thermal resistance junction to ambient	in free air	-	60	-	K/W

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STATIC CHARACTERISTICS $T_j = 25^\circ\text{C}$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_F	Forward voltage	$I_F = 10 \text{ A}$ $I_F = 10 \text{ A}; T_j = 125^\circ\text{C}$	-	1.0 0.79	1.25 0.9	V V
I_R	Reverse current	$V_R = V_{RW\max}$ $V_R = V_{RW\max}; T_j = 125^\circ\text{C}$	-	-	0.5 2.0	mA mA

DYNAMIC CHARACTERISTICS $T_j = 25^\circ\text{C}$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{fr}	Forward recovery voltage	$I_F = 10 \text{ A}; dI_F/dt = 50 \text{ A}/\mu\text{s}$	-	7	11	V
t_{fr}	Forward recovery time	$I_F = 10 \text{ A}; dI_F/dt = 50 \text{ A}/\mu\text{s}; V_F = 5 \text{ V}$	-	250	350	ns
t_r	Reverse recovery time	$I_F = 10 \text{ A}; dI_F/dt = 50 \text{ A}/\mu\text{s}; V_F = 2 \text{ V}$	-	450	600	ns
Q_s	Reverse recovery charge	$I_F = 1 \text{ A}; -dI_F/dt = 50 \text{ A}/\mu\text{s}; V_R \geq 30 \text{ V}$ $I_F = 2 \text{ A}; -dI_F/dt = 20 \text{ A}/\mu\text{s}; V_R \geq 30 \text{ V}$	- -	0.75 4.0	1.0 5.0	μs μC

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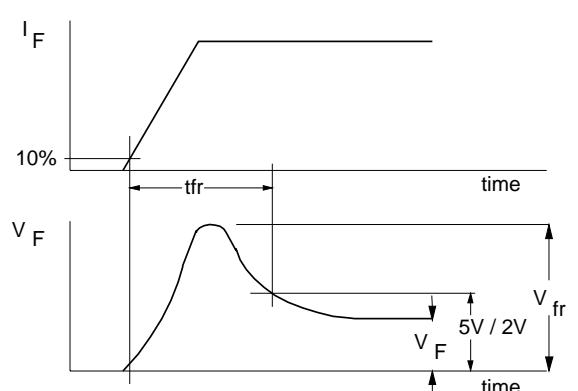
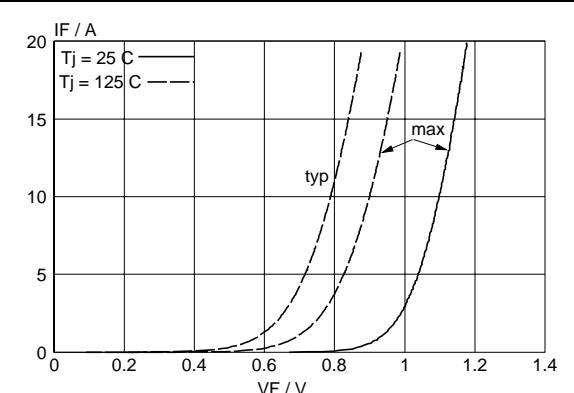
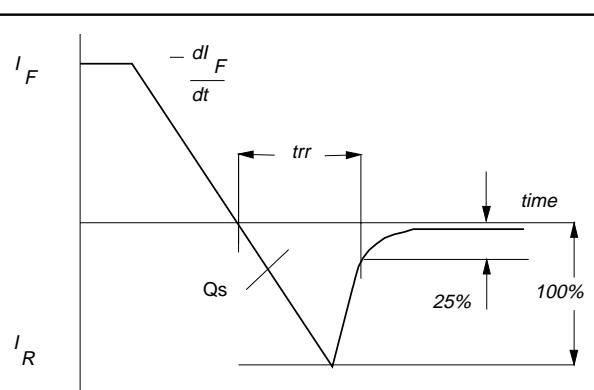
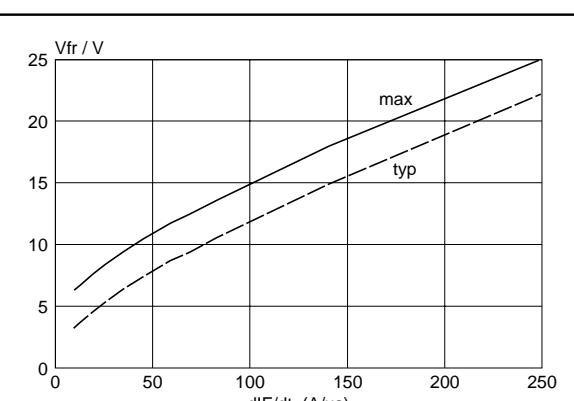
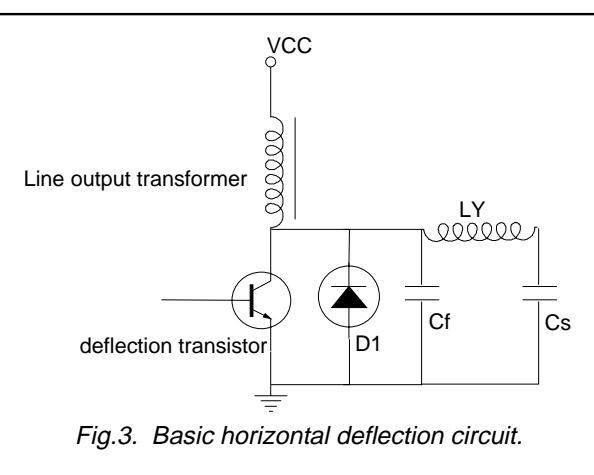
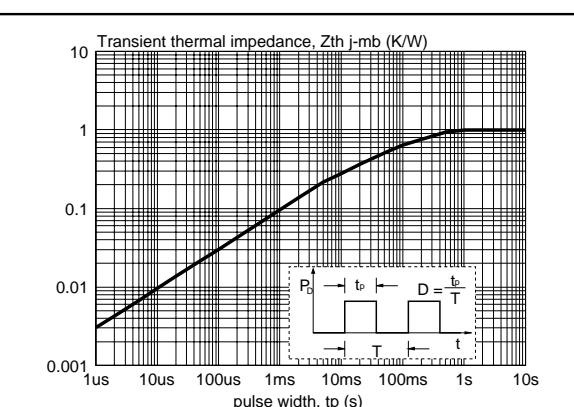
Fig.1. Definition of V_{fr} and t_{fr} Fig.4. Typical and maximum forward characteristic
 $I_F = f(V_F)$; parameter T_j Fig.2. Definition of t_{rr} and Q_s Fig.5. Typical and maximum $V_{fr} = f(dI_F/dt)$; $I_F = 10 A$; $T_j = 25^\circ C$ 

Fig.3. Basic horizontal deflection circuit.

Fig.6. Transient thermal impedance $Z_{th} = f(t_p)$

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MECHANICAL DATA

Dimensions in mm

Net Mass: 2 g

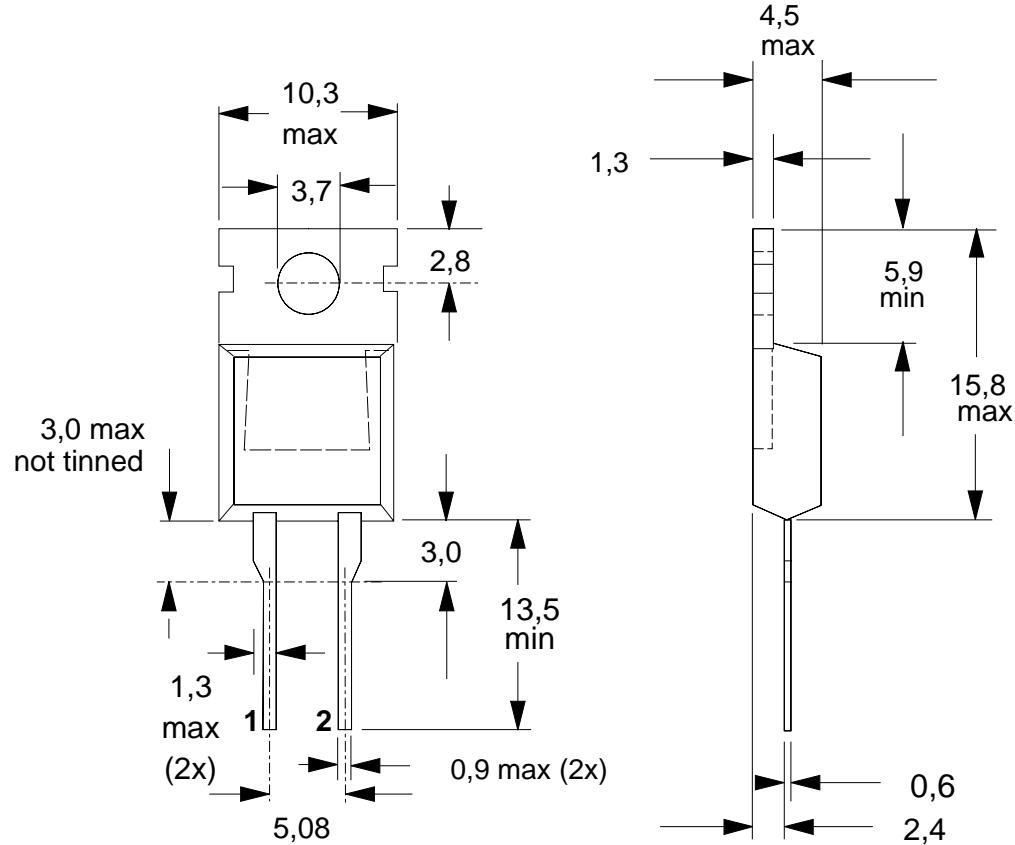


Fig.7. SOD59 (TO220AC). pin 1 connected to mounting base.

Notes

1. Refer to mounting instructions for TO220 envelopes.
2. Epoxy meets UL94 V0 at 1/8".